

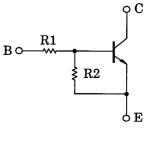
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

### RN1001,RN1002,RN1003 RN1004,RN1005,RN1006

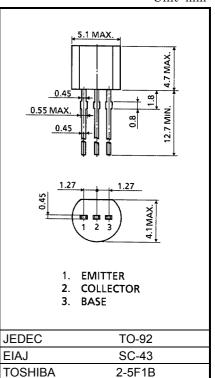
Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2001~RN2006

#### **Equivalent Circuit and Bias Resister Values**



R1 (kΩ)	R2 (kΩ)
4.7	4.7
10	10
22	22
47	47
2.2	47
4.7	47
	4.7 10 22 47 2.2



Weight: 0.21g

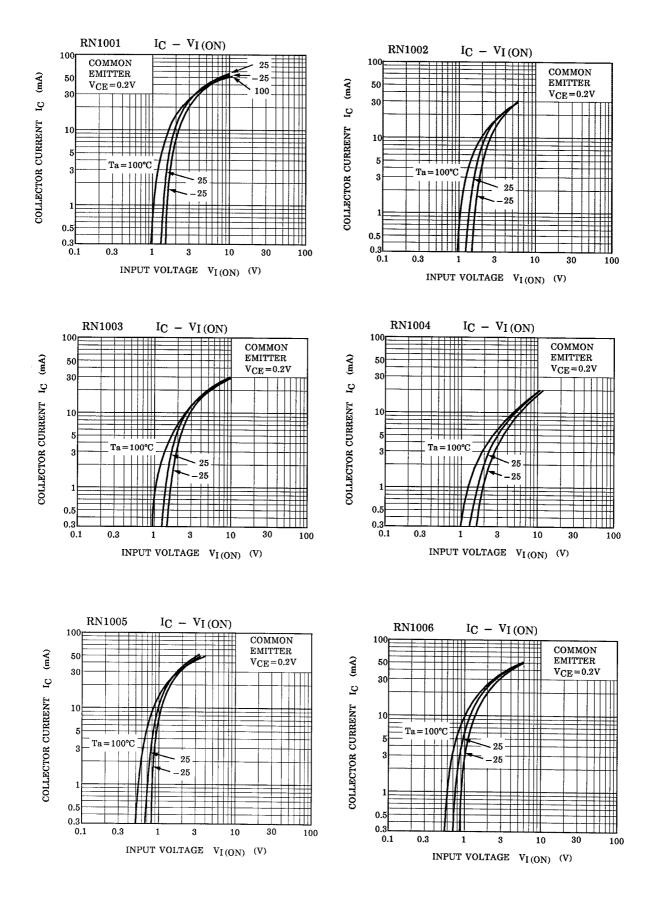
### Maximum Ratings (Ta = 25°C)

Characterist	Symbol	Rating	Unit		
Collector-base voltage	RN1001~1006	V <sub>CBO</sub>	50	V	
Collector-emitter voltage		V <sub>CEO</sub>	50	V	
Emitter base voltage	RN1001~1004	V <sub>FBO</sub>	10	V	
Emitter-base voltage	RN1005, 1006	▲EBO	5		
Collector current		Ι <sub>C</sub>	100	mA	
Collector power dissipation	RN1001~1006	P <sub>C</sub>	400	mW	
Junction temperature	RN1001~1000	Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

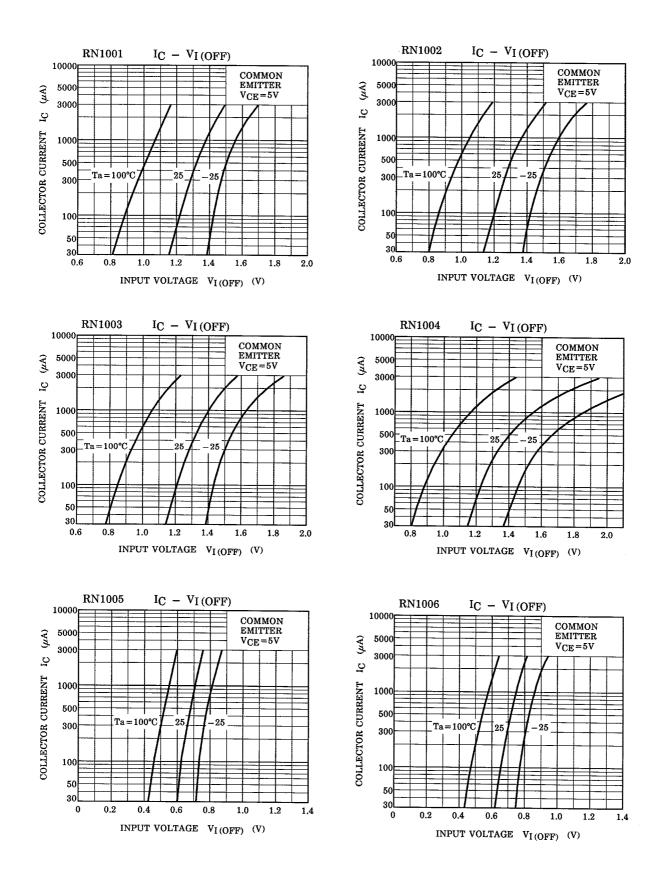
Unit: mm

Electrical Characteristics (Ta = 25°C)

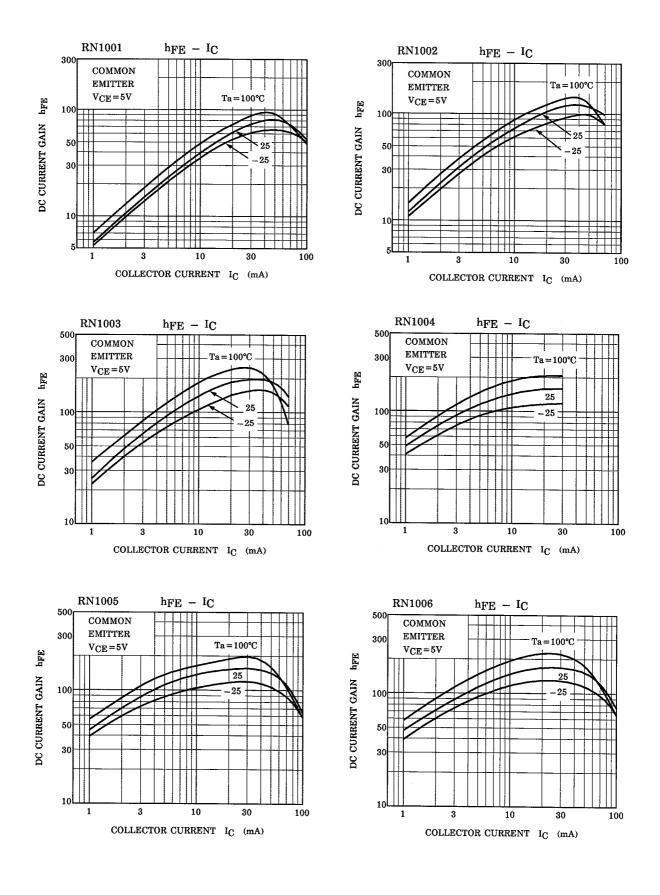
Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit		
Collector cut-off current	RN1001~1006	I <sub>CBO</sub>		V <sub>CB</sub> = 50V, I <sub>E</sub> = 0	-	_	100	n۸		
	KN1001*1000	I <sub>CEO</sub>		V <sub>CE</sub> = 50V, I <sub>B</sub> = 0	-	_	500	nA		
Emitter cut-off current	RN1001	I <sub>EBO</sub> —		V <sub>EB</sub> = 10V, I <sub>C</sub> = 0	0.82	_	1.52	<b>m</b> (		
	RN1002				0.38	_	0.71			
	RN1003				0.17	_	0.33			
	RN1004			0.082	_	0.15	mA			
	RN1005			V <sub>EB</sub> = 5V, I <sub>C</sub> = 0	0.078	_	0.145			
	RN1006				0.074	_	0.138			
	RN1001				30	_	_			
DC current gain	RN1002				50	_	_			
	RN1003				70	_	_			
	RN1004	- h <sub>FE</sub> —	_	$V_{CE} = 5V, I_{C} = 10mA$	80	_	_	_		
	RN1005				80	_	_			
	RN1006				80	_	_			
Collector-emitter saturation voltage	RN1001~1006	V <sub>CE (sat)</sub>	_	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA	_	0.1	0.3	V		
Input voltage (ON)	RN1001			V <sub>CE</sub> = 0.2V, I <sub>C</sub> = 5mA	1.1	_	2.0	V		
	RN1002				1.2	_	2.4			
	RN1003	N/			1.3	_	3.0			
	RN1004	VI (ON) —	_		1.5	_	5.0			
	RN1005				0.6	_	1.1			
	RN1006				0.7	_	1.3			
	RN1001~1004	N/		V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.1mA	1.0	_	1.5	v		
Input voltage (OFF)	RN1005, 1006	V <sub>I (OFF)</sub>	_		0.5	_	0.8			
Transition frequency	RN1001~1006	fT	—	V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA	-	250	—	MHz		
Collector Output capacitance	RN1001~1006	C <sub>ob</sub>	_	$V_{CB} = 10V, I_E = 0, f = 1MH_z$	_	3	6	pF		
	RN1001				3.29	4.7	6.11			
	RN1002				7	10	13			
Input resistor	RN1003			15.4	22	28.6	1.0			
	RN1004	RI	R1 —	-	32.9	47	61.1	kΩ		
	RN1005						1.54	2.2	2.86	
	RN1006				3.29	4.7	6.11			
Resistor ratio	RN1001~1004				0.9	1.0	1.1			
	RN1005	R1/R2	_	_	_		0.0421	0.0468	0.0515	—
	RN1006				0.09	0.1	0.11			



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